Effect of CuI Anode Buffer Layer on the Growth of Polymers Thin Films and on the Performances of Organic Solar Cells*

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ABSTRACT

Organic photovoltaic cells using polymer belonging to the aniline-heteroaryl family as electron donor have been achieved by thermal evaporation. We show that the properties of the polymer film, morphology, molecule order and conductivity depend strongly on the bottom anode buffer layer. While cells without anode buffer layer or with MoO3 or CuI anode buffer layer have been probed, we show that CuI allows improving strongly the cells efficiency through an improvement of the morphology and conductivity of the polymer film. This shows that although it is necessary a good band matching at the interface, this is not sufficient, because the templating effect of CuI on the polymer film is primordial for photovoltaic cells improvement.

Keywords: Organic Solar Cells; Vacuum Thermal Evaporation; Conjugated Polymers; Aniline-Heteroaryl Polymers

1. Introduction

Conjugated organic polymers have been of great interest as an important class of electronic materials because of their high electrical conductivities [1]. Polyaniline is one example which has received a great interest and has been employed in a number of commercial applications [1-4], however, it has no photovoltaic properties due to inadequate band gap for these applications. On the other hand, furan and thiophene are two of the five-membered heteroaromatic ring compounds that have been extensively studied in terms of its reactivity, its specific physicochemical properties, and its technological applications [5-10]. It has attracted particular attention, due to its low band gap value, notwithstanding due to high oxidation potential, difficulty which many authors have overcome by changing the substituents in furan and thiophene rings. In addition, various, co-polymers and biopolymers [11-13] based on polyfuranes and polythiophenes show good stability.

Furan/aniline and Thiophene/aniline based polymers, as poly 4-(2-furanyl)-aniline (P4,2FA) and poly 4-(3-furanyl)-aniline (P4,3FA) and 4-(2-thiophenyl)aniline (P4,2TA) and 4-(3-thiophenyl)aniline (P4,3TA), will exhibit a reduced Eg. Consequently these are materials with photo-electrical properties which could be employed in solar cells. Along with this it is possible to study the effect of different anode buffer layers in the photovoltaic yield when these polymers are used as electron donor in photovoltaic devices.

Organic photovoltaic is nowadays one of the most investigated research field, because of low cost and low temperature process [14]. Smart chemistry can design conjugated polymeric structures for organic photovoltaic cells (OPVCs) and progress has been made in recent years. Nevertheless, most of the materials designed today suffer from the disadvantage of low carrier mobility, which limits the short circuit current of the cells and therefore their efficiency. To solve this problem, different approaches, such as thermal annealing or additives, have been used to improve the carrier mobility. A well known mean consists in the increase of the order present in the layer. The fundamental structure of OPVCs consists in the photoactive layer sandwiched between two electrodes [15]. The photoactive layer can be a bilayer of an electron donor (ED), and an electron acceptor (EA) or a bulk heterojunction consisting of a blend of the two types of organic semiconductors. Indium tin oxide (ITO) is commonly used as transparent conductive anode. In
order to increase the anode work function, which is necessary for efficient hole collection, the ITO surface is subjected to specific treatments, such as oxygen plasma, or coated with a suitable anode buffer layer [16]. Metal, such as gold [17], but also transition metal oxides [18], such as tungsten oxide (WO$_3$) [19], molybdenum oxide (MoO$_3$) [20] and nickel oxide (NiO) [21] have been used as efficient anode buffer layer (ABL). If a lot of works have been dedicated to the improvement of the band matching at the interface anode/organic electron donor, no many works have been devoted to the possibility of templating the organic layer through the use of specific anode buffer layer. As a matter of fact it has been already shown that, in the case of small molecules, it is possible to modify the molecular orientation of the organic layer through the use of specific anode buffer, such as PTCDA [22], Cul [23-25]. In the present study, we show that this result can be generalized to polymers.

Two technological routes are mainly used to grow OPV cells, the deposition of polymers and nanoparticles from solution by spin coating technique and the vacuum sublimation of small molecules and oligomers [26]. The former route has given the concept of bulk heterojunction solar cells (BHJ) [27], while the later gives the multi-heterojunction solar cells family [28]. Compared to spin coating deposition, sublimation under vacuum allows easy purification of organic material. High purity is critical not only for devices performances, but also for long device life time. In addition, vacuum deposition allows facile fabrication of multilayered devices and facile control of the layers thickness [29]. Moreover the templating effect of the substrate, if present, on the organic film structure is amplified by the vacuum deposition process, since in that case the organic material is deposited molecule by molecule onto the substrate. Recently, the vacuum thermal evaporation of poly (3-hexylthiophene) (P3HT) for application in photovoltaic cells has been demonstrated [30,31]. In the present work we widen the field of application of the Cul as templating anode buffer layer to polymers deposited by vacuum sublimation. In order to put in evidence this effect of Cul on the growth of different organic film, we investigated multi-heterojunction solar cells. We show that for different polymers belonging to the aniline-heteroaryl family, a thin Cul buffer layer allows to enhance strongly the OPV cells performance through the improvement of the conductivity of the organic donor, via improvement of the optical absorbance and structural properties of these polymers.

2. Experimental

The chemical syntheses of monomers was made by Suzuki-Miyaura cross coupling between 4-bromoaniline and the heteroaryl boronic acid, respectively, in presence of 10 mol% Pd/C as catalyst and potassium carbonate. Subsequently, the monomers were purified and polymerized using H$_2$IO$_4$ and HClO$_4$ as oxidizing agent mixture [32]. The polymers were dedoped using a solution of NH$_4$OH (pH = 9) for 24 h under stir.

The characterizations of monomers and polymers structures were carried out using NMR and UV-vis spectroscopy. NMR spectra were recorded on a Bruker 400 MHz spectrophotometer using DMSO$_d_6$ as deuterated solvent UV-Vis measurements were carried out on a Cary 5G spectrophotometer.

In the present work, OPVCs studied were the multi-heterojunction: ITO/ABL/ED/C$_{60}$/BCP/Al. In these cells, fullerene (C$_{60}$) and BCP (bathocuproine) have been used as electron acceptor and exciton blocking layer (EBL), respectively. C$_{60}$ is well known as a very efficient electron acceptor. Between the C$_{60}$ and the aluminium cathode, the introduction of EBL improves significantly the OPV cells performances [33]. The ABL was either Cul, MoO$_3$ [34] or MoO$_3$/Cul. Also OPV Cells without ABL have been probed as reference. The different ED used were Poly(4-(2-thiophenaline)) (P4,2TA), Poly (4-(2-furanylaniline)), (P4,2FA), Poly(4-(3-thiophenaline)) (P4,3TA) and Poly(4-(3-furanylaniline)), (P4,3FA), the schemes of these different polymers are presented in Figure 1.

Before thin films deposition, the ITO coated glass substrate was scrubbed with soap, rinsed with distilled water, dried and next placed in the vacuum chamber (10$^{-4}$Pa). The ABL, ED, C$_{60}$, BCP layers were deposited onto the substrate by sublimation and Al were deposited by high vacuum evaporation, without breaking the vacuum. The Cul layer thickness was 3 nm, in the light of earlier works [23], while the MoO$_3$ layer was 4 nm thick [35]. The thickness of the different ED layers has been optimized experimentally. It is, whatever the ED used, 15 nm. Finally, the thickness of the ED, C$_{60}$, and BCP films was 15 nm, 40 nm and 9 nm respectively. The deposition

![Figure 1. Schemes of the different EDs, (a) P4,2TA, (b) P4,3TA, (c) P4,2FA and (d) P4,3FA.](image-url)
rate of the organic material was 0.05 nm/s. The effective area of each cell was 0.16 cm². The thin films thick-
nesses and deposition rates were estimated in situ using a quartz monitor. Finally, the cell arrangement was:

glass/ITO(100 nm)/ABL/ED/C₆₀(40 nm)/BCP(9 nm)/Al(100 nm)

All the chemical products have been provided by Aldrich except for the ED, which have been synthesized in the Pontificia Universidad Católica de Chile, while the ITO glass coated have been provided by SOLEMS, France. The chemical products form Aldrich were used without any purification, the monomer synthesized were purified by chromatography column and crystallization then were polymerized and used as ED in the OPV (a new purification occurred) Indeed, it has been shown that, using the same charge in the evaporation crucible, there is an “auto purification” of the product [36].

In order to try to prevent polymer degradation during deposition, we have measured the temperature of the evaporation boat, using a copper-constantan thermocouple, the weld of the thermocouple being clamped between the body of the crucible and its lid. The thin films structures were analyzed by X ray diffraction (XRD) by a Siemens D5000 diffractometer using Ka radiation from Cu (λKα = 0.15406 nm).

The optical measurements were carried out at room temperature using a Carry spectrometer. The film optical density was measured at wavelengths of 1 to 0.30 μm.

AFM images on different sites of the film were taken ex-situ at atmospheric pressure and room temperature. All measurements have been performed in tapping mode (Nanowizard JPK Instrumens), Classical Silicon-SPM Sensor were used (NCHR, NanoWorld®). The average force constant and resonance were approximately 14 N/m and 330 Hz, respectively. The cantilever was excited at its resonance frequency. The surface roughness Rq (root mean square roughness) of each polymeric surface over its resonance frequency.

The electrochemical work was performed on a Voltamaster model CV 50 W potenciostat/galvanostat, using a conventional three-compartment, three-electrode cell, and a polycrystalline platinum disk (0.07 cm² geometric area) as working electrode. The counter electrode was a coiled Pt wire of large area, separated from the electrolyte solution by a sintered glass. The reference electrode was an Ag/AgCl electrode that matches the potential of the saturated calomel electrode (SCE). Then all potentials quoted in the electrochemical section, are referred to the SCE. The electro-polymerization of each monomer (0.01 mol·L⁻¹) was carried out in anhydrous acetonitrile using tetrabutylammonium hexafluorophosphate (TBAPF₆, 0.1 mol·L⁻¹) as supporting electrolyte. All the system was kept under argon atmosphere and all measurements were performed at room temperature.

Electrical characterizations were performed with an automated I-V tester, in the dark and under sun global AM 1.5 simulated solar illumination. Performances of photovoltaic cells were measured using a calibrated solar simulator (Oriel 300 W) at 100 mW/cm² light intensity adjusted with a PV reference cell (0.5 cm² CIGS solar cell, calibrated at NREL, USA). Measurements were performed at an ambient atmosphere. All devices were illuminated through TCO electrodes [37].

In order to determine the effect of the ABL on the different ED film conductivity, we have investigated the J-V characteristics of hole-only devices with MoO₃ or Cul ABL. These devices were grown using high work-function electrode buffer layers. The hole only devices were fabricated with high work function MoO₃, which is well known to be a hole injector (collector) and a blocking electron layer. Hole only devices have been made using the same ITO covered glass substrate than those used to grow OPV cells. After deposition of the ABL, an ED film thick of 15 nm has been deposited. Then the organic film has been covered with a MoO₃ film thick of 4 nm. Finally aluminium has been used as top electrode.

We have also proceeded to thermal gravimetric analysis (TGA) of the different EDs to determine changes in weight in relation to temperature, in order to check the stability of the polymers at the temperature used for their sublimation. TGA analyses were carried out in a 951 Thermogravimetric Analyser TA-9900 in nitrogen atmosphere (flow rate = 100 mL/min) at a heating rate of 10°C/min.

3. Experimental Results

3.1. NMR Characterization of Monomers and Polymers

To determine the polymerization positions, the polymers were characterized using NMR spectroscopy. The NMR signal that disappears in the NMR of polymer indicates the growth position on the chain [38].

P4.2FA shows in both NMR spectra Figure 2 the signals a and a’ attributed to becenic protons, however, additional signals appears over 7.3 ppm, this correspond to quinoids protons (aniline and furane protons) [38]. The signals c and d in the NMR spectra of monomer remains after the polymerization process but, the signal g of the monomer (proton of carbon 5 of furane ring in monomer numeration) disappears after the polymerization. The
signal d is attributed to linkage of furane-furanate ring as Lére-Porte et al. have reported previously [38,39]. This results indicates that the polymerization of 4,2FA occurs by carbon 5 of furane ring and exist only one furane-furanate linkage because the linkage Nitrogen-Nitrogen of aniline rings is not possible in this kind of polymerization. In the case of 4,3FA the NMR spectra Figure 3 show that after the polymerization of monomer the signals c and d disappears and the signal b remains which h indicates that the polymerization occurs by two positions of furane ring (carbon 2 and 4) of random forms. This produces a branched polymer without presence of quinoids units. This fact prevents a decrease of molecular band gap.

In the case of 4,2TA and 4,3TA the same synthetic behavior is observed as previously we have reported [38]. In this sense the positions of polymerization of 4,2TA, 4,3TA, 4,2FA and 4,3FA is the same respectively i.e. 4,2TA and 4,2FA polymerized by position 5 of heteroaryl ring which produces a non branched polymer. By the other hand 4,3TA and 4,3FA have two positions of polymerization (carbon 2 and 4 of heteroaryl ring) which produces a branched structure. The NMR spectra of 4,2TA and 4,3TA have been previously reported by Zamora et al. [38]. These results suggest that in these polymers the Sulfur or Oxygen atoms of heteroaryl ring have no significant influence in the polymerization process.

3.2. Thermal Gravimetric Analysis and Electrochemical Characterization of the Polymers

Before polymer thin film deposition by sublimation under vacuum, the thermal stability of the different polymers used has been studied by TGA measurements. The results are presented in Figure 4. It can be seen that the weight loss of all the polymers is less than 10% up to 250°C. However the stability depends on the polymers. The P4,2TA is the more stable, with only 5% - 6% of losses of weight at 300°C, while P4,2FA, which is the less stable, has already lost 25% of it weight for the same temperature. Therefore in order to prevent the breaking
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Figure 4. TGA of the different EDs: (a) P4,2TA, (b) P4,3TA, (c) P4,2FA and (d) P4,3FA.

of polymer chains during the deposition process the temperature was limited at 190°C.

On the other hand, in the case of solar cells, after photon absorption and exciton creation, the efficiency of the photo induced charge separation is a key problem. Whatever the structure used, bilayer or bulk heterojunction, the donor and acceptor should have their relative electron affinity (LUMO) and ionisation potential (HOMO) well adapted. The electron affinity of the donor is smaller than that of the acceptor, while the ionisation potential of the acceptor must be significantly greater than that of the donor. When the donor is excited, the electron promoted to the LUMO will lower its energy by moving to the LUMO of the acceptor. The band offset at the organic hetero-interface between the electron-donor material and the electron-acceptor material tends to separate the exciton diffusing to that interface into an electron in the acceptor and a hole in the donor material. Therefore, the knowledge of the HOMO and LUMO of the organic material is very important. When the organic material shows a one electron reversible reduction and oxidation wave, cyclic voltammetry (CV) is recognised as an important technique for measuring band gaps, electron affinities (LUMO) and potential ionisation (HOMO). The oxidation process corresponds to removal of charge from the HOMO energy level whereas the reduction cycle corresponds to electron addition to the LUMO. Moreover, the potential difference $E_g = \text{LUMO} - \text{HOMO}$ can be used to estimate the energy gap of the polymer. Therefore, the HOMO and LUMO energy of the different EDs used in the present work have been estimated before their use in OPVCs. The energy level of the normal hydrogen electrode (NHE) is situated 4.5 eV below the zero vacuum energy level. To estimate the HOMO and LUMO energy, with a correction factor of 4.4 eV [40, 41]:

$$E(\text{HOMO}) = -(E_{\text{ox}}^\text{on} + 4.4) \text{eV}$$

$$E(\text{LUMO}) = -(E_{\text{red}}^\text{on} + 4.4) \text{eV}$$

The different HOMO and LUMO values deduced from cyclic voltammetry measurement are reported in Table 1, polymeric responses were assessed applying a perturbation to the modified electrode in a monomer-free solution of supporting electrolyte $(0.1 \text{ mol \cdot L}^{-1}\text{TBAPF}_6)$ in anhydrous acetonitrile finding in all cases a p-type and n-type doping. No chemical degradation of these states was observed after 10 cycles.

3.3. OPVCs Performances

The performances of the cells using the different EDs are presented in Figure 5, the ABL being used as a parameter. Then, in order to understand the different behaviours, the multilayer structures ITO/ABL/ED have been characterized by XRD, AFM and optical measurements.

Table 1. Optical ($E_g$) and electrochemical ($E_0$) band gap of the different EDs. Their HOMO and LUMO values deduced from electrochemical measurements are also reported.

<table>
<thead>
<tr>
<th>ED</th>
<th>P4,2TA</th>
<th>P4,2FA</th>
<th>P4,3TA</th>
<th>P4,3FA</th>
</tr>
</thead>
<tbody>
<tr>
<td>$E_g$ (eV)</td>
<td>1.55</td>
<td>1.4</td>
<td>2.15</td>
<td>2.0</td>
</tr>
<tr>
<td>$E_0$ (eV)</td>
<td>1.5</td>
<td>1.48</td>
<td>2.2</td>
<td>2.14</td>
</tr>
<tr>
<td>HOMO (eV)</td>
<td>-4.9</td>
<td>-5.16</td>
<td>-5.1</td>
<td>-5.36</td>
</tr>
<tr>
<td>LUMO (eV)</td>
<td>-3.4</td>
<td>-3.68</td>
<td>-2.9</td>
<td>-3.22</td>
</tr>
</tbody>
</table>

Figure 5. Typical J-V characteristics of ITO/ABL/P42TA/ C_{60}/BCP/AI structure, with ABL = ITO/CuI under illumination of AM1.5 solar simu- lation (100 mW/cm²). Inset: enhanced J-V characteristics of the cells using ABL without CuI(ITO, ITO/MoO₃).
Typical results for the four OPVCs configuration used are presented in Figure 5, in the case of P4,2TA as ED. The corresponding values of the short circuit currents ($J_{sc}$), open circuit voltages ($V_{oc}$), fill factors (FF) and cells efficiency ($\eta$) are given in Table 2. The cells presented in each figure have been deposited in the same run. It can be seen that the presence of CuI in the ABL improve strongly the OPVC performances. This improvement is mainly due to the fact that $J_{sc}$ is more than one order of magnitude higher in presence of CuI. There is also a significant improvement of FF, while there is no enhancement of $V_{oc}$ Table 2. All these results in a power cell efficiency (PCE) two orders of magnitude higher when CuI is used as ABL. Even if the overall efficiencies are slightly smaller, the same effect is obtained in the case of P4,2FA (Table 2).

Must be noted that when P4,3TA and P4,3FA are used as ED, the PCE of the cells is very small, however the same improvement in presence of CuI is achieved, from around $2.5 \times 10^{-3}\%$ and $2 \times 10^{-4}\%$ without CuI to $2.5 \times 10^{-2}\%$ and $3 \times 10^{-3}\%$ with CuI in the case of P4,3TA and P4,3FA, respectively. It can be concluded that the solar cell performances are far better when the ITO is recovered with CuI. As it can be seen in Table 2, MoO$_3$, in the case of P4,2TA, improve the OPVC performance and since it is well known that MoO$_3$ allows achieving a good band matching between the ITO anode and the HOMO of the ED, whatever the HOMO value [42], we have tried to optimise the PCE of the OPVCs using a double ABL, MoO$_3$/CuI in our last samples. One can see that this double ABL allows improving significantly the PCE.

### 3.4. Characterization of the ITO/ABL/ED Structures

In order to understand the origin of the strong improvement of the OPVCs performances induced by the presence of a CuI ABL, the structures ITO/ABL/ED, with ABL = MoO$_3$/CuI, or no ABL and ED = P4,2TA, P4,2FA, P4,3TA, P4,3FA, have been submitted to XRD, AFM, optical and hole only electrical characterizations.

All EDs deposited onto the different ABLs have been studied by XRD diffraction. However, well resolved diffraction peaks have been obtained only with P4,2FA. In that case, as it can be seen in Figure 6, the intensity of the diffraction peaks depends on the ABL used. The presence of CuI induces a significant improvement of the intensity of peaks. Also, some new diffraction peaks are visible. Therefore, the presence of CuI induces, not only an improvement of the crystallinity of the deposited films, but also the presence of two crystalline phases of the organic material or at least two different orientations of the crystallites.

This show that, the CuI ABL has a clear templating effect on P4,2FA, it induces some ordered growth of the organic material. Even if not easily visible in the case of the others EDs, the films being often highly disordered, CuI could also modify the growth properties of the organic films. As a mater of fact, this order modification is corroborated by the AFM study. Indeed, the AFM study shows that, even if the root mean square roughness (Rq) of the surface is not strongly modified by the ABL configuration Table 3, the CuI ABL induces a significant decrease of the Rq value, which results in a clear modification of the surface morphology of the polymer film Figure 7.

This effect, which in the case of P4,2FA Figure 7 can be correlated to the modification of the crystalline order in the film, is also clearly visible in the case of the others polymers, as shown for P4,2TA in previous works of Zamora et al. [38]. Therefore it can be inferred that, here also, the order of the organic molecules is modified by

### Table 2. Photovoltaic performance data under AM1.5 conditions of devices using P4,2TA or P4,2FA as ED with different anodes.

<table>
<thead>
<tr>
<th>ED</th>
<th>Anode</th>
<th>$J_{sc}$ (mA/cm$^2$)</th>
<th>$V_{oc}$ (V)</th>
<th>FF (%)</th>
<th>$\eta$ (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>ITO</td>
<td>0.024</td>
<td>0.20</td>
<td>14</td>
<td>$6.7 \times 10^{-4}$</td>
</tr>
<tr>
<td>P4,2TA</td>
<td>ITO/MoO$_3$</td>
<td>0.023</td>
<td>0.34</td>
<td>21</td>
<td>$1.6 \times 10^{-3}$</td>
</tr>
<tr>
<td></td>
<td>ITO/CuI</td>
<td>2.55</td>
<td>0.20</td>
<td>33.5</td>
<td>0.17</td>
</tr>
<tr>
<td></td>
<td>ITO/MoO$_3$/CuI</td>
<td>4.13</td>
<td>0.20</td>
<td>33</td>
<td>0.23</td>
</tr>
<tr>
<td></td>
<td>ITO</td>
<td>0.021</td>
<td>0.42</td>
<td>20</td>
<td>$1.7 \times 10^{-4}$</td>
</tr>
<tr>
<td>P4,2FA</td>
<td>ITO/MoO$_3$</td>
<td>0.017</td>
<td>0.47</td>
<td>16.5</td>
<td>$1.3 \times 10^{-3}$</td>
</tr>
<tr>
<td></td>
<td>ITO/CuI</td>
<td>0.94</td>
<td>0.47</td>
<td>21</td>
<td>0.10</td>
</tr>
<tr>
<td></td>
<td>ITO/MoO$_3$/CuI</td>
<td>0.88</td>
<td>0.36</td>
<td>40.5</td>
<td>0.13</td>
</tr>
</tbody>
</table>

Figure 6. X-ray diffraction diagrams of the ITO/ABL/ P4,2FA structures with ITO,CuI,MoO$_3$/CuI as ABL.
Table 3. Variation of the Rq (root mean square roughness) for the four EDs with the different ABLs.

<table>
<thead>
<tr>
<th>ED</th>
<th>No ABL</th>
<th>MoO$_3$</th>
<th>CuI</th>
</tr>
</thead>
<tbody>
<tr>
<td>P4,2TA</td>
<td>13.33</td>
<td>15.31</td>
<td>8.76</td>
</tr>
<tr>
<td>P4,2FA</td>
<td>13.85</td>
<td>15.66</td>
<td>11.81</td>
</tr>
<tr>
<td>P4,3TA</td>
<td>16.31</td>
<td>15.14</td>
<td>13.06</td>
</tr>
<tr>
<td>P4,3FA</td>
<td>16.67</td>
<td>15.82</td>
<td>12.63</td>
</tr>
</tbody>
</table>

The influence of the ABL on the optical absorbance has been probed. From the example of P4,2TA visualised in Figure 8, it can be seen that there is no clear shift of the absorption spectrum of the film, there is only a slight increase of the absorption in presence of CuI mainly for the small band situated at 440 nm.

The J-V characteristics of the hole only devices are shown in Figure 9. It shows typical curves log (J) against log (V) plots obtained when injecting holes through the ITO contact. Charge transport in these devices is limited to holes. Electron injection from the aluminium electrode can be neglected, due to the large electron barrier due to the MoO$_3$ interlayer. The devices using CuI and MoO$_3$/CuI ABL show largest current density at the same driving voltages as compared to the devices using MoO$_3$ ABL. Clearly the conductivity is enhanced by nearly an order of magnitude when a CuI or MoO$_3$/CuI ABL is used on the place of the MoO$_3$ ABL. For instance when the applied voltage is 10 mV, the current density with MoO$_3$ ABL is $0.047 \text{ mA/cm}^2$, while it is $0.35 \text{ mA/cm}^2$ with CuI ABL.

Therefore, it is clear that the presence of a CuI layer below the organic film induces significant modifications of these organic films, which result in a strong improvement of the solar cells performances in the presence of CuI ABL.

4. Discussion

After First of all, following the works of Kovacik et al. and E. Nasybulin et al. [30,31], we have checked the temperature of the polymer crucible in order to avoid polymer molecule destruction during the sublimation. Since the mass loss of P4,2TA is bellow 5% at 190°C we can conclude that this polymer is not destroyed during the deposition. Moreover, even if there is, probably, some decrease of the molecular weight due to the sublimation process, this decrease is not sufficient to modify strongly the optical properties of the polymer, since the absorption domain of the films is in good agreement with absorption deduced from the band gap estimated by electrochemistry. If this is true for P4,2TA, the case of P4,2FA is different. Actually at 190°C its weight loss is nearly 5%, which means that there is probably some degradation of the polymer, at least a strong decrease of the chain lengths and/or opening of furan ring. It is know that furan ring is less stable than thiophene ring [43]. When furane ring is opened two ketones units are formed (dicarbonyl moiety). This chemical modification pro-
duces more flexibility in the polymeric chains and a lost of conjugation due to the decrease of quinoids and heteroaryl units. Moreover, aniline-thiophene units show more thermal stability in a greater range of temperature due to thiophene ring, which is more aromatic than furane. These degradation of the chain length or furan ring-opening decrease the photovoltaic yield. Therefore P4,2FA films correspond probably to oligomer films. This can explain the crystallization of the films, since films of oligomers crystallize easier than polymer films (Figure 6). Therefore if the partial destruction of the polymer chain during the heating process of P4,2FA can explain that better PCE are achieved with OPVCs using more stable polymer, the fact that it crystallize more easily help us to put in evidence the effect of the different ABL on the growth properties of the films. When deposited onto CuI it is clear that the crystallization of P4,2FA is different from that achieved when it is deposited onto MoO3. The intensity of the diffraction peaks is far higher than that obtained when the films are deposited onto MoO3, which testifies of a better crystallinity of the films deposited onto CuI. After decomposition of the strongest diffraction peak of each diagram, it can be seen that the grain size of the crystallites is more or less the same in each films since the full width at half maximum is around 0.20 degree. This means that the ratio crystallized phase/amorphous phase is higher when the film is deposited onto CuI. Moreover the new peaks visible in the diffraction diagram of the films deposited onto CuI show that a new crystalline phase or at least a new grain orientation is induced by the CuI under layer. The different characterizations of the structures ITO/ABL/ED have shown that CuI modifies the properties of the organic films. The XRD and AFM studies show that the order in the films is significantly improved by the CuI bottom layer. If these modifications have not a broad impact on the optical properties of the films they improve significantly their conductivity. As a matter of fact, if CuI does not induce systematically the crystallization of the polymers, it improves the order of the molecules in the films, which justifies the improvement of the conductivity of the films. It is well known that a limiting factor of the PCE in organic OPVCs is the small conductivity of the organic films. Therefore an increase of this conductivity induces higher short circuit current density and therefore better PCEs.

Another important parameter is the open circuit voltage Voc, it is well known that its maximum value corresponds to the difference between the HOMO of the ED and the LUMO of the acceptor. Therefore, following the results indicated in Table 1 the Voc obtained with P4,2FA must be higher than that achieved with P4,2TA. It can be seen in Table 2 that it is actually the case. However, the PCE of achieved with the cells using P4,2TA as ED is higher than that achieved with P4,2FA, which is due to the smaller Jsc measured. Such disappointing result must be related to the fact that, as shown by the TGA study, P4,2FA is less stable than P4,2TA and it undergoes probably damages during its deposit.

Nevertheless, whatever the polymer used as electron donor, it is clear that CuI improved strongly the OPVCs performances. Since it is known that a MoO3 anode buffer layer allows obtaining good band matching with electron donors, which HOMO value is around 5eV [42], it is clear from the present study that if this condition is necessary it is not sufficient in the case of the polymers studied in the present work. He is necessary furthermore to use an anode buffer layer which improves the morphology and therefore the conductivity of the polymer. In the present case, we show that CuI is very efficient as templating layer. Theses differences in organic film morphology on different substrates are usually attributed to the different interaction between the organic material and the surface of the substrates. Often it is proposed that when the interaction organic molecule-substrate is stronger than the molecule-molecule interaction, the films adopt a lying down configuration (2 dimensions growth of the film). If the molecule-substrate interaction is weak, the molecule-molecule interaction dominates and the molecules adopt a standing up configuration (three dimension growth of the film). For instance, different studies have been done on the influence of the substrate on the molecular orientation of CuPc [44,45]. In the present study, we show that the presence of a thin CuI layer onto the ITO allows controlling the morphology of the polymer films. It has been already shown that CuI and other copper halides can interact easily with organic molecules [46-49]. For instance, complex formation between CuI and organic molecules leads to different π stacking copper halide motifs [46]. More precisely, there is complex formation between copper (I) iodine and nitrogen-donor of the organic molecules. Also, it is well-established that the pymSH/pymS− and bis (2-pyrimidyl)disulfide (pym2S2) ligands are good coordinating ligands toward soft Lewis acids such as Cu (I) and it as been shown that, the solvothermal reactions between pyrimidinedisulfide (pym2S2) and Cu in CH3Cl2:CH3CN lead to the formation of [Cu11I7(pymS)4]n (pymSH = pyrimidine-2(1H)-thione) [47]. Another example is presented in [48] where it is shown that solution reaction of CuI and the ligand L((3-bpfo) [L: 1,3-bis(nicotinoyl) o-phenylenediamine] led to the formation of a novel coordination polymer [CuL(3-bpfo)]] that exhibited an unusual one-dimensio nal helical structure. All these examples show that the CuI exhibits a high tendency to react with an atom donor of organic molecules (as nitrogen, sulphur and oxygen.
5. Conclusion

In order to discuss the effect of CuI on the properties of the polymer films and their corresponding OPVCs, cells with CuI and also with MoO₃ or without ABL have been probed. It is shown that the CuI ABL thin film induces significant improvement of the structural properties of the oligomers, which increases the order in the deposited films and allows strong enhancement of the OPVCs performances due to possible strong Cu-polymer interaction. The PCE achieved with the better polymer of the four EDs of the aniline-heteroaryl family studied in the present work is of the same order of magnitude as those achieved by Kovacik et al. and E. Nasybulin et al. [30,31] with the polythiophene, which is very promising and justifies further working with these materials.

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REFERENCES


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